H01G CAPACITORS; CAPACITORS, RECTIFIERS, DETECTORS, SWITCHING DEVICES OR LIGHT-SENSITIVE DEVICES, OF THE ELECTROLYTIC TYPE (selection of specified materials as dielectric H01B 3/00; {ceramics C04B})

WARNING
In this subclass non-limiting references (in the sense of paragraph 39 of the Guide to the IPC) may still be displayed in the scheme.

2/00 Details of capacitors not covered by a single one of groups H01G 4/00-H01G 11/00
2/02 . Mountings
2/04 . specially adapted for mounting on a chassis
2/06 . specially adapted for mounting on a printed-circuit support
2/065 . {for surface mounting, e.g. chip capacitors}
2/08 . Cooling arrangements; Heating arrangements; Ventilating arrangements
2/10 . Housing; Encapsulation

WARNING
Not complete, see also H01G 4/224

2/103 . {Sealings, e.g. for lead-in wires; Covers}
2/106 . {Fixing the capacitor in a housing}
2/12 . Protection against corrosion (H01G 2/10 takes precedence)
2/14 . Protection against electric or thermal overload (by cooling H01G 2/08)
2/16 . with fusing elements
2/18 . with breakable contacts
2/20 . Arrangements for preventing discharge from edges of electrodes
2/22 . Electrostatic or magnetic shielding
2/24 . Distinguishing marks, e.g. colour coding

4/00 Fixed capacitors; Processes of their manufacture (electrolytic capacitors H01G 9/00)
4/002 . Details
4/005 . . electrodes
4/008 . . Selection of materials
4/0085 . . . {Fried electrodes}
4/01 . . Form of self-supporting electrodes
4/012 . . Form of non-self-supporting electrodes
4/015 . . Special provisions for self-healing
4/018 . . Dielectrics
4/02 . Gas or vapour dielectrics
4/04 . Liquid dielectrics
4/06 . Solid dielectrics
4/08 . . . Inorganic dielectrics
4/085 . . . . {Vapour deposited}
4/10 . . . . . Metal-oxide dielectrics (H01G 4/085 takes precedence)
4/105 . . . . . {Glass dielectric}
4/12 . . . . . Ceramic dielectrics (H01G 4/085 takes precedence; ceramic materials per sec C04B 35/00)
4/1209 . . . . . {characterised by the ceramic dielectric material (H01G 4/1272, H01G 4/1281 take precedence)}
4/1218 . . . . . {based on titanium oxides or titanates (H01G 4/1245 takes precedence)}
4/1227 . . . . . {based on alkaline earth titanates}
4/1236 . . . . . {based on zirconium oxides or zirconates (H01G 4/1263 takes precedence)}
4/1245 . . . . . {containing also titanates}
4/1254 . . . . . {based on niobium or tungsten, tantalum oxides or niobates, tantalates}
4/1263 . . . . . {containing also zirconium oxides or zirconates}
4/1272 . . . . . {Semiconductive ceramic capacitors}
4/1281 . . . . . {with grain boundary layer}
4/129 . . . . . {containing a glassy phase, e.g. glass ceramic}
4/14 . . . . . Organic dielectrics
4/145 . . . . . {vapour deposited}
4/16 . . . . . of fibrous material, e.g. paper
4/18 . . . . . of synthetic material, e.g. derivatives of cellulose (H01G 4/16 takes precedence)
4/183 . . . . . {Derivatives of cellulose (H01G 4/145 takes precedence)}
4/186 . . . . . {halogenated (H01G 4/145 takes precedence)}
4/20 . . . . . using combinations of dielectrics from more than one of groups H01G 4/02 - H01G 4/06 (H01G 4/12 takes precedence)
4/203 . . . . . {Fibrous material or synthetic material}
4/206 . . . . . {inorganic and synthetic material}
4/22 . . . . . impregnated
4/221 . . . . . {characterised by the composition of the impregnant}
4/222 . . . . . {halogenated}
4/224 . . . Housing; Encapsulation
4/228 . . . Terminals
Capacitors in which the capacitance is varied by mechanical means, e.g. by turning a shaft; Processes of their manufacture

5/00 Capacitors in which the capacitance is varied by mechanical means, e.g. by turning a shaft; Processes of their manufacture

5/01 . . . Details
5/011 . . . Electrodes
5/012 . . . at least one of the electrodes being a displaceable liquid or powder
5/013 . . . Dielectrics
5/0132 . . . [Liquid dielectrics]
5/0134 . . . [Solid dielectrics]
5/0136 . . . [with movable electrodes]
5/0138 . . . [with movable dielectrics]
5/014 . . . Housing; Encapsulation
5/015 . . . Current collectors
5/017 . . . Temperature compensation
5/019 . . . Means for correcting the capacitance characteristics

2005/02 . . . [IPC5 having air, gas, or vacuum as the dielectric]
5/04 . . . using variation of effective area of electrode
5/06 . . . due to rotation of flat or substantially flat electrodes
5/08 . . . becoming active in succession

5/10 . . . due to rotation of helical electrodes
5/12 . . . due to rotation of part-cylindrical, conical, or spherical electrodes
5/14 . . . due to longitudinal movement of electrodes
5/145 . . . [with profiled electrodes]
5/16 . . . using variation of distance between electrodes
5/18 . . . due to change in inclination, e.g. by flexing, by spiral wrapping
5/38 . . . Multiple capacitors, e.g. ganged
5/40 . . . Structural combinations of variable capacitors with other electric elements not covered by this subclass, the structure mainly consisting of a capacitor, e.g. RC combinations (RC-filters H03H)

7/00 Capacitors in which the capacitance is varied by non-mechanical means; Processes of their manufacture (capacitors with potential jump or surface barrier H01L 29/00)

7/02 . . . Electrolytes, e.g. having a permanently-polarised dielectric
7/021 . . . [having an organic dielectric]
7/023 . . . [of macromolecular compounds]
7/025 . . . [having an inorganic dielectric]
7/026 . . . [with ceramic dielectric]
7/028 . . . [having a heterogeneous dielectric]
7/04 . . . having a dielectric selected for the variation of its permittivity with applied temperature
7/06 . . . having a dielectric selected for the variation of its permittivity with applied voltage, i.e. ferroelectric capacitors (electrets H01G 7/02)

9/00 Electrolytic capacitors, rectifiers, detectors, switching devices, light-sensitive or temperature-sensitive devices; Processes of their manufacture

9/0003 . . . [Protection against electric or thermal overload; cooling arrangements; means for avoiding the formation of cathode films (H01G 9/12 takes precedence)]
2009/0007 . . . [Double layer capacitors]
2009/001 . . . [Temperature sensitive devices]
2009/0014 . . . [Solid electrolytic capacitors]
2009/0018 . . . [with wound foil electrodes]
2009/0021 . . . [Skin fibre]
2009/0025 . . . [Liquid electrolytic capacitors]
9/0029 . . . [Processes of manufacture]
9/0032 . . . [Formation of the dielectric layer (anodisation in general C25D)]
9/0036 . . . [Formation of the solid electrolyte layer]
9/004 . . . Details
9/008 . . . Terminals
9/012 . . . specially adapted for solid capacitors
9/016 . . . [specially adapted for double-layer capacitors]
9/02 . . . Diaphragms; Separators
9/022 . . . Electrolytes, absorbents (electrolytic or electrophoretic processes, apparatus therefor C25; for primary, secondary or fuel cells H01M)
9/025 . . . [Solid electrolytes (H01G 11/54 takes precedence)]
9/028 . . . . . . Organic semiconducting electrolytes, e.g. TCNQ
9/032 . . . . . . Inorganic semiconducting electrolytes, e.g. MnO₂
9/035 . . . . . . Liquid electrolytes, e.g. impregnating materials (H01G 11/54 takes precedence)
Solid electrolytic capacitors (H01G 11/00 takes precedence)  
Liquid electrolytic capacitors (H01G 11/00 takes precedence)  

**WARNING**  
This group is no longer used for classification of new documents as from October 1, 2012. The backfile is being continuously reclassified to group H01G 11/54.

Electrodes (or formation of dielectric layers thereon)  
[characterised by the material (alloys in general see C22C)]  
[on Al basis]  
(characterised by the structure)  
(characterised by their structure)  
(characterised by the material)  
(characterised by the structure)  
(characterised by aluminium)  
(characterised by their structure)  
[consisting of tantalum, niobium, or sintered material; Combinations of such electrodes with solid semiconductive electrolytes, e.g. manganese dioxide]  

**WARNING**  
This group is no longer used for classification of new documents as from October 1, 2012. The backfile is being continuously reclassified to group H01G 11/22.

Sintered electrodes  
(Powder therefor (metallic powder in general B22F))  
Etched foil electrodes  
(specially adapted for double-layer capacitors)

**WARNING**  
This group is no longer used for classification of new documents as from October 1, 2012. The backfile is being continuously reclassified to group H01G 11/22.

Mounting in containers  

**WARNING**  
This group is no longer used for classification of new documents as from October 1, 2012. The backfile is being continuously reclassified to group H01G 11/22.

Dielectric layers  
Housing; Encapsulation  
Sealing, e.g. of lead-in wires  
Vents or other means allowing expansion  
Structural combinations (or circuits) for modifying, or compensating for, electric characteristics of electrolytic capacitors (impedance networks H03H)  
Liquid electrolytic capacitors (H01G 11/00 takes precedence)  
Solid electrolytic capacitors (H01G 11/00 takes precedence)  
(with wound foil electrodes)  
(Skin fibre)

**WARNING**  
This group is no longer used for classification of new documents as from October 1, 2012. The backfile is being continuously reclassified to group H01G 11/54 and its subgroups.

Specially for use as rectifiers or detectors (H01G 9/22 takes precedence)  
Self-interrupters  
Light-sensitive devices  
(characterised by the electrolyte, e.g. comprising an organic electrolyte)  
(Solid electrolytes)  
(the electrolyte comprising liquid ionics, e.g. alkyl imidazolium iodide)  
(characterised by the ionic charge transport species, e.g. redox shuttles)  
(characterized by the counter electrode)  
(comprising an oxide semiconductor electrode)  
(comprising titanium oxide, e.g. TiO$_2$ (H01G 9/2036 takes precedence))  
(comprising mixed oxides, e.g. ZnO covered TiO$_2$ particles)  
(comprising zinc oxides, e.g. ZnO (H01G 9/2036 takes precedence))  
(comprising a semiconductor electrode comprising elements of the fourth group of the Periodic System (C, Si, Ge, Sn, Pb) with or without impurities, e.g. doping materials)  
(comprising a semiconductor electrode comprising AII-BV compounds with or without impurities, e.g. doping materials)  
(comprising a semiconductor electrode comprising All-BVI compounds, e.g. CdTe, CdSe, ZnTe, ZnSe, with or without impurities, e.g. doping materials (H01G 9/2027 takes precedence))  
(comprising an organic dye as the active light absorbing material, e.g. adsorbed on an electrode or dissolved in solution)  
(comprising a mixture of two or more dyes)  
(Panel or arrays of photoelectrochemical cells, e.g. photovoltaic modules based on photoelectrochemical cells)  
(comprising two or more photoelectrodes sensible to different parts of the solar spectrum, e.g. tandem cells)  
(Sealing arrangements, e.g. to prevent the leakage of the electrolyte)  
(Serial interconnection of cells)  
(Photovoltaic chemical cells in the form of a fiber)  
(Light trapping arrangements)  
(comprising a flexible sustrate)  
(Temperature-sensitive devices)  
(Devices using combined reduction and oxidation, e.g. redox arrangement or solion)  
(Structural combinations of electrolytic capacitors, rectifiers, detectors, switching devices, light-sensitive or temperature-sensitive devices with each other)
**WARNING**

Groups H01G 11/00 - H01G 11/86 are incomplete pending reclassification of documents from groups H01M 12/00 and H01M 12/005.

All groups listed in this Warning should be considered in order to perform a complete search.

11/02 . . using combined reduction-oxidation reactions, e.g. redox arrangement or solion
11/04 . Hybrid capacitors
11/06 . . with one of the electrodes allowing ions or anions to be reversibly doped thereinto, e.g. lithium-ion capacitors [LICs]
11/08 . Structural combinations, e.g. assembly or connection, of hybrid or EDL capacitors with other electric components, at least one hybrid or EDL capacitor being the main component
11/10 . Multiple hybrid or EDL capacitors, e.g. arrays or modules (housings, cases or mountings thereof H01G 11/78)
11/12 . . Stacked hybrid or EDL capacitors
11/14 . Arrangements or processes for adjusting or protecting hybrid or EDL capacitors (emergency protective circuit arrangements specially adapted for capacitors, and effecting automatic switching in the event of an undesired change from normal working conditions H02H 7/16; emergency protective circuit arrangements for limiting excess current or voltages without disconnection H02H 9/00)
11/16 . . against electric overloads, e.g. including fuses
11/18 . . against thermal overloads, e.g. heating, cooling or ventilating
11/20 . . Reformations or processes for removal of impurities, e.g. scavenging
11/22 . Electrodes
11/24 . . characterised by structural features, e.g. forms, shapes, surface areas, porosities or dimensions, of the materials making up or comprised in the electrodes; characterised by the structural features of powders or particles used therefor
11/26 . . characterised by the structures of the electrodes, e.g. multi-layered, shapes, dimensions, porosities or surface features
11/28 . . . arranged or disposed on a current collector; Layers or phases between electrodes and current collectors, e.g. adhesives
11/30 . . characterised by their materials
11/32 . . . Carbon-based, e.g. activated carbon materials
11/34 . . . . characterised by carbonisation or activation of carbon
11/36 . . . Nanostructures, e.g. nanofibres, nanotubes or fullerenes

**NOTE**

Group H01G 11/02 takes precedence over groups H01G 11/04 - H01G 11/14